NSN 5962-01-375-2540

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View Online at https://aerobasegroup.com/nsn/5962-01-375-2540

Body Length:

Between 1.230 inches and 1.280 inches

Body Width:

Between 0.245 inches and 0.310 inches

Body Height:

Between 0.095 inches and 0.185 inches

Maximum Power Dissipation Rating:

660.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

3-state output and high speed and low power and w/disable and high performance and ultraviolet erasable and high impedance

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

14 input

Current Rating Per Characteristic:

120.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

5.00 input pascal industrial light tank stock and 8.00 output pascal industrial light tank stock

Time Rating Per Chacteristic:

45.00 nanoseconds access

Memory Device Type:

Eprom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

